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## 1 Introduction

Owing to the ability to drive and control fluid flow, $<sup>1</sup>$  the Mar-</sup> angoni effect<sup> $2-5$ </sup> has been applied in many technologies, including self-assembly, $6,7$  coating, $8-10$  and Marangoni drying.11,12 Marangoni drying can realize the drying of wafers by Marangoni-driven flow after a sequence of wet cleaning processes, and it has been widely employed in the manufacturing of integrated circuits (ICs).<sup>13</sup> When a wafer is withdrawn from a deionization (DI) water bath, a meniscus and an entrained water film are induced on the wafer surface, as shown in Fig. 1. Meanwhile, an organic vapour from an extra source is blown at the meniscus, and gives rise to a downward Marangoni stress. This can drive the water flow from the contact line to the bath, leading to a much thinner residual water film without contaminants compared with the traditional drying techniques.14,15 Therefore, Marangoni drying achieves an ultraclean surface. Although Marangoni drying is widely utilized in the industry, its mechanism remains elusive. As the technology node of the IC shrinks to less than 14 nm, the requirements for cleaning the wafer surface become increasingly critical. Further improvement of the drying performance strongly depends on the comprehensive understanding of Marangoni drying.

Huethorst and Marra<sup>14,15</sup> observed the dynamic wetting behaviour of sessile droplet on the hydrophilic substrate in the

# Evolution of entrained water film thickness and dynamics of Marangoni flow in Marangoni drying

Changk[u](http://orcid.org/0000-0002-1630-7651)n Li, Dewen Zhao,\* Jialin Wen, Jie Cheng and Xinchun Lu D<sup>\*</sup>

As an ultra-clean wafer drying technique, Marangoni drying has been widely applied in the integrated circuits manufacturing process. When the wafer is vertically withdrawn from a deionization water bath, Marangoni stress along the meniscus, which is induced by the organic vapour, strips off the water film entrained on the wafer surface, and the wafer drying is thereby realized. In this work, a numerical model is presented that is comprised of the film, meniscus, and bulk regions for Marangoni drying. The model combines the transfer of organic vapour from air to water and the withdrawal of the wafer from the bath. The evolution of the entrained water film thickness, the tangential velocity, and the stress at the air–water interface are quantitatively investigated. The results reveal that the thickness of the entrained water film is reduced by more than one order of magnitude compared with the wafer withdrawn process without the Marangoni effect. In addition, owing to the receding of the contact line, it is found that the capillary pressure gradient dramatically increases, which contributes to the sudden increase in the tangential velocity in the dynamic meniscus. Moreover, the tangential velocity decreases in the static meniscus adjacent to the dynamic meniscus, which results from the redistribution of the interfacial concentration of the organic species driven by the Marangoni flow. PAPER<br> **EVOLUtion of entrained water film thickness and<br>
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organic vapour. The result showed that the Marangoni effect gives rise to the receding of the contact line and thus a nonzero apparent contact angle. Hernández-Sánchez et al.<sup>16</sup> investigated the spreading of a circular thin region in the horizontal water film driven by the Marangoni effect through the continuous supply of isopropanol–water droplets. It was found that the law of radius growth and the depression in the film depend on the Marangoni stress and viscous force. In addition, the residual water film thickness after Marangoni drying was indirectly measured. In the vapour supplying ways of vapour blown at the meniscus and diffusion in semi-quiescent environment, the minimum residual thicknesses are 14 nm and 110 nm, respectively.<sup>14</sup> The results suggested that the minimum residual



Fig. 1 Principle of Marangoni drying

State Key Laboratory of Tribology, Tsinghua University, Beijing 100084, China. E-mail: xclu@tsinghua.edu.cn; zhaodw@tsinghua.edu.cn

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film is much thinner than the thickness of 200 nm in the traditional spinning drying technology.<sup>17</sup> These experimental investigations have elucidated the basic physical principle of Marangoni drying. However, it is difficult to conduct a direct observation or quantitative analysis of the dynamics of Marangoni drying, such as the interfacial flow and the stress in the meniscus under the geometries of the wafer withdrawn and gas–liquid mass transfer.

The numerical simulation has been an effective method to quantitatively examine the Marangoni-driven flow. The Marangoni effect induced by the surfactant in the solution during the dip-coating process has received considerable attention.<sup>18-20</sup> The results revealed that the Marangoni effect realizes the thickening of entrained film, and the film-thickening factor is larger than one.<sup>21-23</sup> Although Marangoni drying is similar to this issue, the solution of Marangoni drying are much challenging because of the dramatic reduction of entrained film thickness by 10 to 100 times compared with dip-coating without the Marangoni effect. $24$  The previous numerical investigations of Marangoni drying are based on lubrication approximation.<sup>25</sup> Thess and Boos<sup>26</sup> proposed a model for Marangoni drying, where the mass transport of the organic vapour was ignored and the distribution of surface tension was prescribed to be a linear function of position, and the results suggested that the residual film monotonically decreases in accordance with the surface tension gradient. Furthermore, Matar and Craster<sup>27</sup> proposed numerical models which coupled the gas–liquid mass transfer behaviour of the organic vapour and the wafer withdrawn from a bath. In their work, the distribution of the surface tension and the morphology evolution in the thin film region were obtained. These studies emphasized the hydrodynamics of the thin film with the Marangoni effect and established the foundation for elucidating the Marangoni drying mechanism. However, the study of the flow field and the flow dynamics in the meniscus, which are significant to revealing the dynamic process of Marangoni-driven flow, have not been fully addressed in quantitative terms in Marangoni drying. **BSC Advances**<br>
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In this paper, a Marangoni drying model that considers the film, meniscus, and bulk regions is proposed. Firstly, the evolution of the thickness of entrained water film is investigated. In addition, the flow field in the meniscus and the timespatial evolution of the tangential velocity at the whole interface are quantitatively examined. Furthermore, the Marangoni stress, Marangoni number, and capillary pressure gradient are analysed to interpret the evolution law of the interfacial flow mechanism. Moreover, the effects of the withdrawing velocity and vapour source on the drying performance are discussed. The results of this work are expected to contribute to the comprehensive understanding of the Marangoni drying process.

### 2 Model formulation

The adopted model with consideration of a wafer vertically withdrawn from a DI water reservoir with a constant velocity of  $V_0$  is shown in Fig. 2. The wafer is withdrawn along the y axis by a height of  $H_3$ , and a water film is entrained on the wafer surface



Fig. 2 Schematic of the computational domain (A–F) and the Cartesian coordinate system.

with the thickness of  $h_i$ , which is initially unknown. Furthermore, the film, meniscus and bulk regions are contained in this model. The meniscus contains two regions: the dynamic meniscus and the static meniscus. In the static meniscus, the morphology is steady during the wafer withdrawn process. The dynamic meniscus is the intermediate region that connects the flat film region and the curved static meniscus region.<sup>28</sup> The intersection point between the film and the dynamic meniscus region is defined as the contact line in the two-dimensional model. The air-water interface ranges from  $s = 0$  to  $s = s_{\rm e}$ , and the variable s is the interfacial length. The interface of bulk water region and air is specified as the horizontal.

It is assumed that the organic vapour is diffused from a linemass source at  $(x_0, y_0)$  in the quiescent environment referencing Matar's model, $27$  which corresponds with the regime of the 'semi-quiescent vapour in the environments' in previous experiments. In this work, it is assumed that the wafer is perfectly wetted with the contact angle of zero. Because the direct evaporation of water will give rise to the watermarks, the evaporation in Marangoni drying is inhibited.<sup>29</sup> Therefore, the thermal Marangoni effect induced by evaporation is neglected.

#### 2.1 Governing equations

Both the DI water and the air are Newtonian fluids with constant densities and dynamic viscosities. The velocity field in Cartesian coordinates is  $u = (u, v)$ . The air-water two-phase flow is described using the full Navier–Stokes equations and the continuity equation, which are formulated in the Arbitrary Lagrangian–Eulerian (ALE) frame. The ALE frame combines the advantages of Eulerian (fixed in space) and Lagrangian (etched into material) methods. It enables the mesh nodes to move with material for accurately tracing the interface, while also to fix in space to avoid the immense deformation inside the material.<sup>30</sup> The descriptions of the mesh and material velocities are

 $u(X_\text{m},t)=\frac{\partial x}{\partial t}\Big|_{X_\text{m}}$  and  $u(X,t)=\frac{\partial x}{\partial t}\Big|_{X},$  respectively, where  $X_\text{m}$  and  $X$ are the respective mesh and material coordinates. The convective velocity  $u_c$  in the mesh coordinate can be obtained using the chain rule, which was previously described in detail.<sup>31</sup> Here, we refer to the result as follows:

$$
u_{\rm c}=u(X,\,t)-u(X_{\rm m},\,t)\tag{1}
$$

The governing equations in the ALE frame are as follows:

 $(1)$  The two-phase flow is described by the Navier–Stokes equations and continuity equation,

$$
\rho_{k}\left(\frac{\partial \boldsymbol{u}}{\partial t} + \boldsymbol{u}_{c} \cdot \nabla \boldsymbol{u}\right) = \nabla \cdot \left[-p\boldsymbol{I} + \mu_{k}\left(\nabla \boldsymbol{u} + \left(\nabla \boldsymbol{u}\right)^{T}\right)\right] + \rho_{k}\boldsymbol{g} \quad (2)
$$

$$
\nabla \cdot \mathbf{u} = 0 \tag{3}
$$

for  $k = g$ , l, which represent air and water, respectively. The gravity in air is neglected.

(2) The transfer of organic vapour from a line-mass source to the interface in air is described by the diffusion equation, $27$ 

$$
\frac{\partial c_{\rm g}}{\partial t} + \nabla \left( -D_{\rm g} \nabla c_{\rm g} \right) = Q_0 \cdot \delta(\mathbf{x} - \mathbf{x}_0) \cdot f(t) \tag{4}
$$

where  $c_g$  and  $D_g$  are the concentration and the diffusion coefficient of the organic vapour in air, respectively.  $\delta(\mathbf{x} - \mathbf{x}_0)$  is a delta function and  $\mathbf{x}_0 = (x_0, y_0)$  is the location of the vapour source.  $f(t)$  is a function in time t, which represents the start of organic vapour blowing from the source. Paper<br>
MCA  $\omega = \frac{1}{2\pi} \int_{0}^{1} \text{ and } u(X, t) = \frac{du}{dx} \int_{0}^{1} \text{, respectively, where } X = \text{ and } Y = X = Y$ <br>
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$$
f(t) = \begin{cases} 0, & t = 0 \\ 1, & t > 0 \end{cases} \tag{5}
$$

 $Q_0$  is produced by line-mass source  $q_0$ , which is shown as a point located at  $(x_0, y_0)$  in the two-dimensional model. It is given by:

$$
\lim_{\delta S} \int_{\delta S} Q_0 = q_0 \tag{6}
$$

(3) In the DI water phase, the concentration of the organic species is governed by the convection–diffusion equation,

$$
\frac{\partial c_1}{\partial t} + \mathbf{u}_c \cdot \nabla c_1 = \nabla (D_1 \nabla c_1)
$$
 (7)

where  $c_1$  and  $D_1$  are the concentration and the diffusion coefficient of the organic species in water, respectively.

(4) At the air–water interface, the concentration of the organic species satisfies the mass balance equation; that is, $32$ 

$$
\frac{\partial c_s}{\partial t} + \nabla_s \cdot ((\boldsymbol{u}_c)_s c_s) - (\nabla_s \cdot \boldsymbol{n}) c_s (\boldsymbol{u}_c \cdot \boldsymbol{n}) = D_s \nabla^2 c_s + R_s \qquad (8)
$$

where  $\nabla_{\mathbf{s}} = (\mathbf{I} - \mathbf{n}\mathbf{n}) \cdot \nabla = \mathbf{I}_{\mathbf{s}} \cdot \nabla$  is the surface gradient operator,  $\mathbf{n}$ denotes the outward normal vector on the specified boundary,  $u<sub>s</sub> = I<sub>s</sub> \cdot u$  is the tangential velocity, and  $(u<sub>c</sub>)<sub>s</sub>$  represents the tangential convection velocity in the ALE.

#### 2.2 Boundary condition

2.2.1 Two-phase flow.  $(1)$  On the moving wafer surface, the nonslip boundary condition is employed. At the film exit boundary ( $0 \le x \le h_i$ ), it is assumed that the outflow velocity is approximately equal to the wafer withdrawing velocity.

(2) The flow at the lateral boundary ( $x = H_1, -H_2 \le y \le 0$ ) in water is assumed to occur along the negative  $x$  direction, and the boundary stress is<sup>21</sup>

$$
\boldsymbol{T}_{1} \cdot \boldsymbol{n} = \left(\rho_{1} g y + 2\mu_{1} \frac{\partial u}{\partial x}\right) \boldsymbol{e}_{x} + \mu_{1} \frac{\partial u}{\partial y} \boldsymbol{e}_{y}
$$
(9)

The gravity in air is neglected; thus, the lateral boundary condition in air  $(x = H_1, 0 \le y \le H_3)$  is

$$
\boldsymbol{T}_{g} \cdot \boldsymbol{n} = \left(2\mu_{g}\frac{\partial u}{\partial x}\right)\boldsymbol{e}_{x} + \mu_{g}\frac{\partial u}{\partial y}\boldsymbol{e}_{y}
$$
(10)

where  $T_1$  and  $T_g$  are the total stress tensor of water and air, respectively, and  $e_x$  and  $e_y$  denote the unit vector along the x and y directions.

(3) The flow at the bottom boundary ( $y = -H_2$ ,  $0 \le x \le H_1$ ) is assumed to occur along the positive  $y$  direction. Hence, we specify the boundary stress as follows:<sup>21</sup>

$$
\boldsymbol{T}_{1} \cdot \boldsymbol{n} = \rho_{1} g H_{2} \boldsymbol{e}_{y} - \mu_{1} \frac{\partial v}{\partial x} \boldsymbol{e}_{x}
$$
 (11)

(4) At the top boundary of the air phase  $(y = H_3, h_i \le x \le H_1)$ , we assume that the air above the water is infinite and the open boundary condition is utilized; that is,

$$
T_g \cdot n = 0 \tag{12}
$$

(5) At the air–water interface, the boundary stress is speci fied.<sup>33</sup> The force balance in the normal direction is

$$
(\boldsymbol{n} \cdot \boldsymbol{T}_{g} - \boldsymbol{n} \cdot \boldsymbol{T}_{1}) \cdot \boldsymbol{n} = \sigma(\nabla \cdot \boldsymbol{n}) - \Pi \tag{13}
$$

Where  $\Pi$  is the disjoining pressure, which depends on the intermolecular force.<sup>28</sup>

$$
\Pi = A/(6\pi h^3) \tag{14}
$$

where  $A$  and  $h$  are the Hamaker constant and the film thickness, respectively. The stress in the tangential direction is induced by the surface tension gradient, which is the so-called Marangoni effect,

$$
(\boldsymbol{n} \cdot \boldsymbol{T}_{\rm g} - \boldsymbol{n} \cdot \boldsymbol{T}_{\rm l}) \cdot \boldsymbol{t} = -\nabla_{\rm s} \sigma \cdot \boldsymbol{t} \tag{15}
$$

where  $t$  denotes the tangential vector on the interface.

(6) On the interface ( $0 \le s \le s_e$ ), the kinematic condition is specified as<sup>30</sup>

$$
\boldsymbol{u} \cdot \boldsymbol{n} = \frac{\partial \boldsymbol{x}}{\partial t} \bigg|_{X_{\text{m},\text{s}}} \cdot \boldsymbol{n} \tag{16}
$$

where  $\frac{\partial x}{\partial t}\Big|_{X_{\text{max}}}$  is the velocity of the nodes at the air-water interface.

2.2.2 Gas–liquid mass transfer. (1) The top and lateral boundaries in the air as well as the bottom boundary in the water phase are specified as open boundaries.

(2) The top and lateral boundaries in the water phase are the outflow boundaries; that is,

$$
-\boldsymbol{n} \cdot D_{\mathrm{l}} \nabla c_{\mathrm{l}} = 0 \tag{17}
$$

 $(3)$  The flux of vapour from air to the interface and from the interface to water are  $R_1$  and  $R_2$ , respectively. Therefore, the net flux  $R_s$  at the air-water interface is<sup>27</sup>

$$
R_{\rm s} = R_1 - R_2 = (k_{\rm gs}c_{\rm g} - k_{\rm sg}c_{\rm s}) - (k_{\rm sl}c_{\rm s} - k_{\rm ls}c_{\rm l}) \tag{18}
$$

where  $k_{\rm gs}$  and  $k_{\rm sg}$  are the adsorptive mass transfer coefficients of the organic species from the air to the interface and the desorptive one returning to the air, respectively. Similarly,  $k_{sl}$ and  $k_{\text{ls}}$  are the adsorptive mass transfer coefficients from the interface to the water and the desorptive one returning into the interface, respectively.<sup>27</sup> The interfacial concentration is dominated by the ratio of the coefficient of desorption and adsorption at the interface, which is  $\kappa = k_{\rm sl} \cdot x_0/k_{\rm gs}$ , where  $x_0$  is the distance from the vapour source to the wafer surface.

(4) The dependence of the interfacial concentration on the surface tension is described by an exponential equation, $27,34$ 

$$
\sigma = \sigma_0 e^{-(\beta c_s)} \tag{19}
$$

where  $\beta$  is the concentration coefficient of surface tension representing the ability of the organic vapour to alter the surface tension.

2.2.3 ALE. In the ALE method, the displacement or velocity of the mesh on the boundary is specified in advance. Then, a Laplace smoothing method is implemented to introduce the influence of the boundary nodes to the internal ones. The Laplace smoothing method in the transient case is

$$
\begin{cases}\n\frac{\partial}{\partial X_{\rm m}}^2 \frac{\partial x}{\partial t} + \frac{\partial}{\partial Y_{\rm m}}^2 \frac{\partial x}{\partial t} = 0\\ \n\frac{\partial}{\partial X_{\rm m}}^2 \frac{\partial y}{\partial t} + \frac{\partial}{\partial Y_{\rm m}}^2 \frac{\partial y}{\partial t} = 0\n\end{cases}
$$
\n(20)

The movements of the nodes on the boundaries are specified as follows:

(1) On the bottom boundary, the displacements of the mesh in x and y directions are specified as zero:  $dx = 0$  and  $dy = 0$ .

(2) On the lateral boundary and moving wall boundary, the displacement of the mesh in the x direction is fixed  $(dx = 0)$ .

(3) On the exit boundary of water and the top boundary of air, the displacement of the mesh in the y direction is fixed (dy = 0).

#### 2.3 Initial condition

The initial condition of Marangoni drying is difficult to directly obtain; thus, we divide the Marangoni drying into two steps. The first one is to solve the classic problem of the wafer withdrawn from an infinite bath (dip coating) without organic species to obtain the approximate steady-state solution with

a series of withdrawing velocities  $(V_0)$ . The thickness of  $h_i$  is assumed to be 0.1 mm. In this step, the velocity field, pressure, interfacial morphology, and value of film thickness  $h_0$  are obtained.

In the second step, we choose the results of dip coating as the initial conditions to solve the Marangoni drying problem, which couples the two-phase flow with the gas-liquid mass transfer of the organic vapour. In this study,  $t = 0$  s is the start time of blowing the organic vapour from the source. The value of the constants and range of the parameters are given in Table 1.

#### 2.4 Numerical method

Finite element method (FEM) is employed to discretize the equations and boundary conditions. The computing domain is tessellated using the triangular elements. The Lagrange linear elements are implemented for all the dependent variables of velocity, pressure, and concentration. Because of the immense deformation of the air–water interface, the mesh quality becomes poor and the algorithm will not be able to converge. Therefore, an automatic remeshing method is utilized to establish new meshes when the mesh quality degrades below a specified level of 0.1. The iteration continues with the new reference configuration with high-quality meshes until the iteration is complete.<sup>30</sup> The numerical work is implemented in COMSOL Multiphysics. Additionally, the mesh sensitivity analysis is conducted, and the residual film thickness is obtained with a different number of grids. The results in Table 2 show that the relative deviation of the residual film thickness is less than 0.2% when the number of grids increases from 806 064 to 966 020, thereby obtaining the results that are independent of the grid size. **EXALUATEST**<br> **EXALUATE THE SECTION CONDUCTS ARTICLE CONSIDENT CONDUCTS ARTICLE CONSIDENT CONDUCTS IN THE SECTION CONDUCTS ARTICLE CONSIDER THE CREATIVE CONSIDERATIVE CONSIDERATIVE CONSIDERATIVE CONSIDERATIVE CONSIDERATIV** 

Table 1 Value of physical constants and the range of parameters<sup>27</sup>

Constant	Value	parameter	range
$\rho_1$ (kg m <sup>-3</sup> ) $\rho_{\rm g}$ (kg m <sup>-3</sup> ) $\mu$ <sub>1</sub> (Pa s) $\mu_{\rm g}$ (Pa s) $\sigma_0$ (N m <sup>-1</sup> ) $D_g$ $(m^2 s^{-1})$ $D_{\rm s}$ (m <sup>2</sup> s <sup>-1</sup> ) $D_1$ $(m^2 s^{-1})$ A(J)	10 <sup>3</sup> 1.205 $10^{-3}$ $10^{-5}$ 0.072 $10^{-5}$ $10^{-9}$ $10^{-9}$ $10^{-19}$	$V_0$ (mm s <sup>-1</sup> ) $k_{\rm gs}$ (m s <sup>-1</sup> ) $\kappa(1)$ $k_{\rm ls}$ (m s <sup>-1</sup> ) $q_0$ (mol m <sup>-1</sup> s <sup>-1</sup> ) $\beta$ (m <sup>2</sup> mol <sup>-1</sup> )	$0.4 - 20$ $10^{-2} - 1$ $0 - 0.01$ $0 - 10^{-6}$ $10^{-4}$ -10 <sup>-2</sup> $0.5 - 4$

#### Table 2 Mesh sensitivity analysis



# 3 Results and discussion

### 3.1 Evolution of entrained water film thickness

3.1.1 Model validation. To validate the accuracy of the proposed model, the initial film thickness was first compared with the Landau–Levich  $[LL]$  theory,<sup>35</sup> which predicts the thickness of the entrained film when a plate is withdrawn vertically from a liquid bath without the Marangoni effect. As shown in Fig. 3a, the initial thickness of entrained water film  $h_0$ obtained from the full Navier–Stokes equations agrees well with that from the LL theory.26,36 In addition, the evolution of entrained water film thickness was compared with that of Matar's study.<sup>27</sup> The non-dimensional parameters in that model were transferred in this study into the dimensional ones as follows:  $k_{gs} = 40 \text{ m s}^{-1}$ ,  $k_{sl} = 20 \text{ s}^{-1} x_0 = 2 \text{ mm}$ ,  $t = 1.25 \text{ s}$ ,  $V_0 =$ 20, 4, 0.4 mm  $\rm s^{-1}.$  The residual parameters that we used were  $q_0$  $= 2.5 \times 10^{-3}$  mol  $(m^{-1} s)$  and  $\beta = 3$  m<sup>2</sup> mol<sup>-1</sup>. In the present model, the value of water film thickness at the top boundary  $(y$  $=$   $H_3$ ) is specified as the film thickness h since it is the furthest position from the horizontal. It is thus the closest to the flat film region. Paper<br> **S** Result is and discussion<br>
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As shown in Fig. 3b, the evolution law of  $h$  in the present model matches well with that of Matar, especially for  $V_0 = 0.4$ 



3.1.2 Effect of  $V_0$  and  $q_0$  on the thickness of water film. Because Marangoni drying is a transient problem, the solution time depends on the withdrawing velocity and the height of the withdrawn wafer (the film region). In this study, the drying time is specified as

$$
t_{\rm e} = (H_3 - H_{\rm M})/V_0 \tag{21}
$$

where  $H_M$  is the height of the meniscus, which is approximately equal to 3 mm. For example, the required drying time is 3 s when  $H_3$  and  $V_0$  are 6 mm and 1 mm  $\rm s^{-1}$ , respectively. The initial film thickness at  $t = 0$  s was obtained to solve the dip-coating problem without the Marangoni effect at the specified withdrawing velocity. The remaining film after drying  $(t = t_e)$  is defined as the residual film.

As shown in Fig. 4a, the entrained water film thickness monotonously reduces with continuously blowing of the organic vapour. The film thickness initially rapidly reduces and



Fig. 3 (a) Comparison of the present model and the Landau–Levich theory for the initial thickness of the entrained water film. (b) Comparison of the present model and Matar's model for the evolution of the entrained water film.



Fig. 4 (a) Evolution of the film thickness during Marangoni drying with different  $q_0$ . (b) Residual film thickness after drying with different  $V_0$ and  $q_0$ .

then becomes much slower since the film reduction leads to the increase in the viscous force, which resists the further film reduction. The parameters used were specified as  $k_{\rm gs}$  = 0.8 m s<sup>-1</sup>,  $k_{sg} = k_{ls} = 0$ ,  $\kappa = 2 \times 10^{-4}$  and  $\beta = 3$  m<sup>2</sup> mol<sup>-1</sup>. As shown in the previous experimental results with the vapour supply method of 'vapour diffusion in a semi-quiescent environment', the residual thicknesses of entrained water film with the withdrawing velocity of 0.7 mm  $s^{-1}$  and 1.5 mm  $s^{-1}$  are 110 nm and 160 nm, respectively. In the present model, the thickness of residual film with  $V_0 = 1$  mm s<sup>-1</sup> and  $q_0 = 2.5 \times$  $10^{-4}$  mol (m<sup>-1</sup> s<sup>-1</sup>) is 148 nm, which validates that the prediction of the water film thickness using the present model is reliable. The thinning effect of water film thickness is more dramatic with the increase in the vapour source. Additionally, the increase in the withdrawing velocity leads to not only the increase of the viscosity force, but also the decrease of the necessary drying time. Therefore, the Marangoni effect is weaker and the residual film after drying remarkably thickens (Fig. 4b). BSC Advances<br>
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#### 3.2 Dynamics of Marangoni flow

To elucidate the evolution mechanism of the entrained water film, the dynamics of Marangoni flow, including the flow field in the meniscus and the tangential velocity at the whole air– water interface, were investigated.

3.2.1 Flow field in the meniscus. Firstly, the flow field in the meniscus was investigated. Fig. 5 shows the distribution of streamline whose density presents the magnitude of velocity. When there is no Marangoni effect (Fig. 5a), the backflow driven by the capillary pressure gradient and gravity are comparable



Fig. 5 Evolution of the flow field in the meniscus during the drying process.

with the upward flow induced by the viscous force. Therefore, the shape of the streamline is an inverted 'V'. However, once the Marangoni effect occurs, the backflow along the interface becomes much stronger than the flow along the wafer surface. Thus, the water in the film region is dragged back into the meniscus. In addition, the maximum velocity moves away from the meniscus and the region adjacent to the wafer decreases gradually (the streamline is sparse). Owing to the tangential stress along the curved meniscus and the viscous force along the wafer, a vortex occurs; moreover, it moves away from the meniscus region during the drying process.

3.2.2 Tangential velocity. To quantitatively analyse the tangential flow, the evolution of the tangential velocity at the whole interface, including the film, meniscus, and horizontal, is discussed. As shown in Fig. 6a, there exist significant differences in these three regions. The tangential velocity is small in the film region, while it increases remarkably in the meniscus region, and then decreases in the horizontal region.

The maximum value of the tangential velocity  $V_{\text{max}}$  increases and gradually flows away from the meniscus. In particular, the tangential velocity increases suddenly in the dynamic meniscus when the drying time  $t$  is large than 1.5 s and then it reduces to be smaller than that of  $t < 1.5$  s in the static meniscus adjacent



Fig. 6 (a) Distribution of the tangential velocity at the whole interface. (b) The tangential velocity at the last moment of the drying process with different values of  $V_0$  and  $q_0$ . (a1) and (b1) are the corresponding tangential velocities in the dynamic meniscus.

to the dynamic meniscus. This phenomenon is enhanced during the drying process. As shown in Fig. 6b, the maximum tangential velocities at the last moment of the drying process are located in the identical position for the same withdrawing velocity and thus for the same drying time. Furthermore, the maximum velocity at the last moment of the drying process increases with the vapour source,  $q_0$ . Furthermore, the maximum tangential velocity of  $V_0 = 5$ ,  $q_0 = 1.25 \times 10^{-3}$  is much smaller than that in the case of  $V_0 = 1, q_0 = 2.5 \times 10^{-4}$ , although the total concentration of the blown organic vapour in these two cases are the same. Paper<br>
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3.2.3 Mechanism of interfacial flow. In general, the interfacial flow is dominated by the viscous force induced by the wafer withdrawn, surface tension gradient, and capillary effect in the meniscus.<sup>27</sup> To understand the interfacial flow mechanism, the time–spatial evolution of the Marangoni stress, Marangoni number (ratio of Marangoni stress and viscous force), and capillary pressure gradient in the meniscus were investigated.

3.2.3.1 Marangoni stress. The expression of Marangoni stress is

$$
T_{\rm s} = -\sigma_0 \beta e^{-\beta c_s} \frac{\mathrm{d}c_s}{\mathrm{d}s} \tag{22}
$$

As shown in Fig. 7a, the interfacial concentration decreases monotonously from  $s = 0$  to the horizontal region, and the interfacial concentration at the whole interface increases with the continual supply of the organic vapour. The concentration at the contact line alters remarkably and thus the Marangoni stress is the largest. Furthermore, the concentration gradient in

the static meniscus adjacent to the dynamic meniscus reduces gradually, and the Marangoni stress reduces correspondingly. Subsequently, another maximum point occurs in the static meniscus and gradually moves towards the horizontal. The evolution of the Marangoni stress accounts for the redistribution of the concentration driven by the tangential flow, which, in turn, gives rise to the reduction in the concentration gradient.<sup>37</sup> This is the reason for the reduction in the tangential velocity in the static meniscus adjacent to the dynamic meniscus.

As shown in Fig. 7c, the interfacial concentration increases with the enhancement of  $q_0$  under the same withdrawing velocity. Moreover, the higher  $q_0$  gives rise to a higher velocity of Marangoni flow. Therefore, more organic molecules are carried along with the tangential flow from the higher concentration position to the lower one. As a result, the distribution of the interfacial concentration and the Marangoni stress in the meniscus for different values of  $q_0$  tend to be parallel to each other (Fig. 7c). This is the reason that the position of  $V_{\text{max}}$ depends on the drying time (Fig. 6b).

3.2.3.2 Marangoni number. The Marangoni number was introduced to investigate the competition behaviour of the Marangoni stress and the viscous force induced by the wafer withdrawn.<sup>38,39</sup>

$$
M_{\rm a} = \frac{T_{\rm s}}{\mu \frac{V_0}{h}} = \frac{T_{\rm s} \cdot h}{\mu V_0} \tag{23}
$$

Owing to the immense variation in thickness from the film to the meniscus region, the single characteristic length in the



Fig. 7 Time–spatial distributions of (a) the interfacial concentration and (b) the corresponding Marangoni stress. Effects of  $V_0$  and  $q_0$  on the distribution of (c) the interfacial concentration and (d) the corresponding Marangoni stress at the last moment of the drying process.

Marangoni number is not available. Additionally, the real-time value of the film thickness  $(x_h)$  is assigned to the h when  $x_h$  is less than the capillary length  $(l_c)$ . Otherwise,  $l_c$  is utilized and the expression is

$$
h = \begin{cases} x_h, & 0 \le x_h < l_c \\ l_c, & x_h \ge l_c \end{cases} \tag{24}
$$

As shown in Fig. 8a, the Marangoni number in the film region is much smaller than that in the meniscus, and it decreases gradually in the static meniscus with time. Its maximum is away from the meniscus. Therefore, in the film region, the viscous force is the dominated factor with respect to the tangential velocity, whereas, in the meniscus region, the Marangoni stress becomes the dominated one because of the reduction of viscous force. The migration of the maximum value of the Marangoni number and the decrease in the static meniscus result from the redistribution of the interfacial concentration (Fig. 7b). Fig. 8b shows that the Marangoni number under the higher  $V_0$  is much smaller than that under the lower one, although the Marangoni stress is similar in the film and meniscus regions. This is the reason that the tangential velocity is much smaller under the higher  $V_0$  in Fig. 6b.



Fig. 8 (a) Time–spatial evolution of the Marangoni number during the drying process. (b) Marangoni number at the last moment of the drying process with different values of  $V_0$  and  $q_0$ 

3.2.3.3 Capillary pressure gradient. The Marangoni effect not only gives rise to the tangential flow, but also induces the evolution of the interfacial morphology.<sup>26</sup> As shown in Fig. 9a, the contact line recedes gradually driven by the Marangoni flow resisting the viscous force. This results in the dramatic increase of the curvature in the dynamic meniscus region. Fig. 9b shows that the movement of the contact line is much further with an increase in the Marangoni stress for the same  $V_0$ , and the locations of the contact line for the same total concentration of the blown organic vapour are remarkably different when we compare the case of  $V_0 = 5$ ,  $q_0 = 1.25 \times 10^{-3}$  with  $V_0 = 1$ ,  $q_0 =$  $2.5 \times 10^{-4}$ .

In the previous study, it was found that the upward Marangoni stress along the meniscus resulted in the stretching of the dynamic meniscus and thus the decrease in the capillary pressure gradient.<sup>22</sup> In contrast, in Marangoni drying the downward Marangoni stress may have induced the receding of the contact line and the shrinking of the dynamic meniscus, leading to a dramatic increase in capillary pressure. To verify this, the time–spatial evolution of capillary pressure was examined along the meniscus. Fig. 10a shows the capillary pressure (the negative value) from the film to the meniscus region, which changes dramatically in the dynamic meniscus. Fig. 10b shows that the rapid variation of capillary pressure in the dynamic meniscus leads to a high pressure gradient in the tangential direction, which drives the tangential flow from the high-pressure region to the low-pressure one. Consequently, it promotes the water flow from the film region to the meniscus and thus the reduction of the film thickness. The capillary pressure gradient is higher when the contact line recedes further; hence, it results in a more dramatically sudden increase in the tangential velocity. Furthermore, it is found that the pressure gradient is very small when  $t$  is smaller than 1.5 s, and then it increases dramatically. This is consistent with the evolution of tangential velocity in the dynamic meniscus in Fig. 6a1. Fig. 10c also indicates that the stronger Marangoni effect leads to a more remarkable receding of the contact line and a much larger capillary pressure gradient. As a result, the pressure gradient has an important effect on the tangential velocity, and this is the reason for the sudden increase in the tangential velocity in the dynamic meniscus. **BSC Advances**<br>
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Fig. 9 (a) Time–spatial evolution of the interfacial morphology at dynamic meniscus; (b) Interfacial morphology at the last moment of the drying process with different values of  $V_0$  and  $q_0$ .



Fig. 10 Time-spatial evolution of (a) the interfacial pressure and (b) the pressure gradient in the dynamic meniscus. The distribution of (c) the pressure and (d) the pressure gradient at the last moment of the drying process with different values of  $V_0$  and  $q_0$ .

### 4 Conclusions

A numerical model of Marangoni dying with consideration of the film, meniscus, and bulk regions was developed and herein presented. The model combines the wafer withdrawn and the organic vapour transfer across the air–water interface from a vapour source. The evolution of the entrained water film thickness, flow field, and tangential velocity were quantitatively investigated. Furthermore, the Marangoni stress, Marangoni number, and capillary pressure gradient were analysed to reveal the mechanism of interfacial flow.

The findings in this paper show that the residual film thickness after drying is monotonously reduced by more than one order of magnitude, and the evolution of entrained water film thickness agrees well with the previous studies. In addition, the time–spatial evolution of the tangential velocity shows the obvious differences in the film, meniscus, and horizontal regions, which result from the differences in the competitive behaviours of Marangoni stress and viscous force induced by the wafer withdrawn in these regions. Furthermore, the tangential velocity increases along the meniscus, and the maximum tangential velocity increases and moves towards the horizontal. Particularly, it is found that the tangential velocity increases suddenly in the dynamic meniscus and then decreases remarkably in the static meniscus adjacent to the dynamic meniscus. The sudden increase in the tangential velocity in the dynamic meniscus results from the receding of the contact line and the shrinking of the dynamic meniscus, which lead to the dramatic increase in the capillary pressure gradient in the tangential direction. The decrease in tangential

velocity in the static meniscus adjacent to the dynamic meniscus results from the redistribution of the interfacial concentration of the organic species driven by the Marangoni flow and thus the decrease in the Marangoni stress in this region.

The analysis of the water film evolution with the parameters of withdrawing velocity and vapour source, as well as the discussion of Marangoni flow dynamics, are expected to provide useful guidance for the controlling of this process and the designing of the Marangoni dryer.

# Conflicts of interest

There are no conflicts of interest to declare.

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